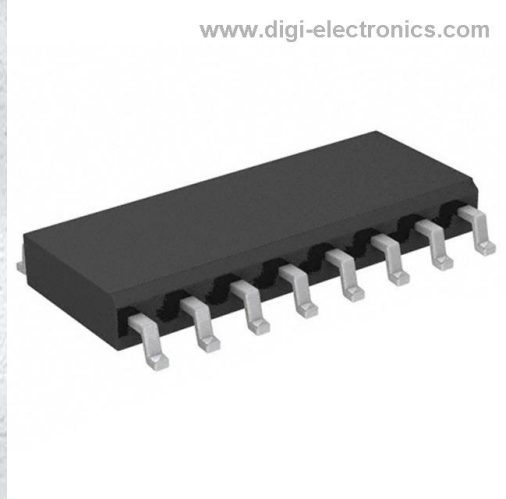
IL 260-3 Datasheet



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DiGi Electronics Part Number	IL 260-3-DG
Manufacturer	NVE Corp/Isolation Products
Manufacturer Product Number	IL 260-3
Description	DGTL ISO 2500VRMS 5CH GP 16SOIC
Detailed Description	General Purpose Digital Isolator 2500Vrms 5 Channel 110Mbps 30kV/µs CMTI 16-SOIC (0.154", 3.90mm Width)

This model IL 260-3 is available at DiGi Electronics.

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Manufacturer Product Number:	Manufacturer:
IL 260-3	NVE Corp/Isolation Products
Series:	Product Status:
IsoLoop®, IL260	Active
Technology:	Type:
GMR (Giant Magnetoresistive)	General Purpose
Isolated Power:	Number of Channels:
No	5
Inputs - Side 1/Side 2:	Channel Type:
5/0	Unidirectional
Voltage - Isolation:	Common Mode Transient Immunity (Min):
2500Vrms	30kV/µs
Data Rate:	Propagation Delay tpLH / tpHL (Max):
110Mbps	15ns, 15ns
Pulse Width Distortion (Max):	Rise / Fall Time (Typ):
3ns	1ns, 1ns
Voltage - Supply:	Operating Temperature:
3V ~ 5.5V	-40°C ~ 85°C
Mounting Type:	Package / Case:
Surface Mount	16-SOIC (0.154", 3.90mm Width)
Supplier Device Package:	Base Product Number:
16-SOIC	IL 260

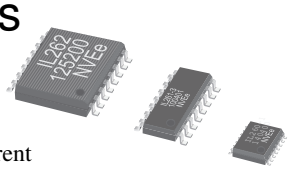
Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	5A991A
HTSUS:	
8542.39.0001	

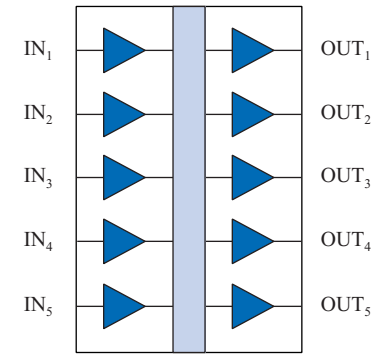
NVE CORPORATION

IL260/IL261/IL262

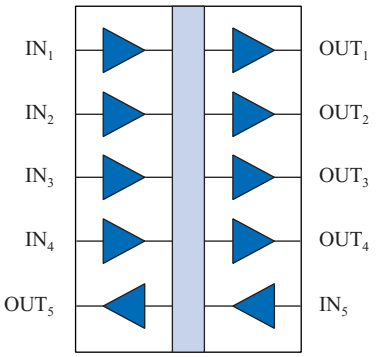
High Speed Five-Channel Digital Isolators



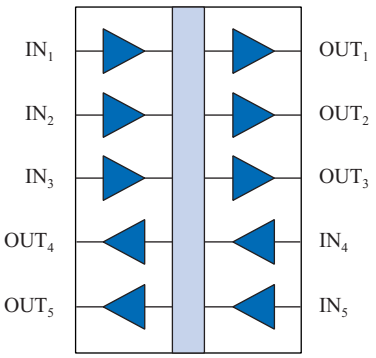
Functional Diagrams



IL260



IL261



IL262

Features

- High Speed: 110 Mbps
- 1.2 mA/channel typical quiescent current
- Very high isolation: 6 kV_{RMS} Reinforced Isolation (VE-Series)
- 50 kV/µs typ.; 30 kV/µs min. common mode transient immunity
- No carrier or clock for low EMI emissions and susceptibility
- –40 to 85 °C operating temperature
- 44000-year barrier life
- Excellent magnetic immunity
- 2 ns typical pulse width distortion
- 100 ps pulse jitter
- 4 ns typical propagation delay skew
- 10 ns typical propagation delay
- 2 ns channel-to-channel skew
- IEC 60747-17 (VDE 0884-17):2021-10 certified; UL 1577 recognized
- 0.15" and True 8™ mm 16-pin SOIC; 16-pin QSOP packages

Applications

- ADCs and DACs
- Multiplexed data transmission
- Board-to-board communication
- Peripheral interfaces
- Equipment covered under IEC 61010-1 Edition 3
- >5 kV_{RMS} rated IEC 60601-1 medical applications

Description

NVE's IL260-Series five-channel high-speed digital isolators are CMOS devices manufactured with NVE's patented* spintronic Giant Magnetoresistive (GMR) technology.

A unique ceramic/polymer composite barrier provides excellent isolation and virtually unlimited barrier life.

Performance is specified over the temperature range of –40 °C to +85 °C without derating. All transmit and receive channels operate at 110 Mbps over the full temperature and supply voltage range. The symmetric magnetic coupling barrier provides a typical propagation delay of only 10 ns and a pulse width distortion of 2 ns, achieving the best specifications of any isolator. The fifth channel can be is used to distribute isolated clocks or handshake signals to multiple delta-sigma A/D converters.

Parts are available in ultraminiature 16-pin QSOPs, as well as 0.15"and 0.3"-wide SOIC packages. V-Series versions offer extremely high isolation voltage of 6 kV_{RMS}, and true 8 mm creepage.

High channel density and low jitter, skew, and pulse-width distortion makes these devices ideal for isolating ADCs and DACs, parallel buses and peripheral interfaces.

REV. Y

Absolute Maximum Ratings(1)

Parameters	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Storage Temperature	T_S	−55		150	°C	
Junction Temperature	T_J	−55		150	°C	
Supply Voltage	V_{DD1},V_{DD2}	−0.5		7	V	
Input Voltage	V_I	−0.5		V_{DD} + 0.5	V	
Output Voltage	V_O	−0.5		V_{DD} + 0.5	V	
Output Current Drive	I_O	−10		10	mA	
Lead Solder Temperature				260	°C	10 sec.
ESD			2		kV	HBM

Recommended Operating Conditions

Parameters	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Ambient Operating Temperature	T_A	−40		85	°C	
Junction Temperature	T_J	−40		100	°C	
Supply Voltage	V_{DD1},V_{DD2}	2.7		5.5	V	
Logic High Input Voltage	V_{IH}	2.4		V_{DD}	V	
Logic Low Input Voltage	V_{IL}	0		0.8	V	
Input Signal Rise and Fall Times	t_{IR}, t_{IF}			1	µs	

Safety and Approvals

IEC 60747-17 (VDE 0884-17):2021-10:

"VE" version (Reinforced Isolation; VDE File Number 5016933-4880-0002)

- Working Voltage (V_{IORM}): 1200 V_{RMS} (1700 V_{PK}) with 20% Safety Factor; pollution degree 2
- Isolation voltage (V_{ISO}): 6000 V_{RMS}
- Surge immunity (V_{IOSM}): 12.8 kV_{PK}
- Surge rating: 8000 V
- Transient overvoltage (V_{IOTM}): 6000 V_{PK}
- Each part tested at 2387 V_{PK} for 1 second, 5 pC partial discharge limit
- Samples tested at 6000 V_{PK} for 60 sec.; then 2122 V_{PK} for 10 sec. with 5 pC partial discharge limit

Standard versions (Basic Isolation; VDE File Number 5016933-4880-0001)

- Isolation voltage (V_{ISO}): 2500 V_{RMS}
- Transient overvoltage (V_{IOTM}): 4000 V_{PK}
- Surge rating: 4000 V
- Each part tested at 1590 V_{PK} for 1 second, 5 pC partial discharge limit.
- Samples tested at 4000 V_{PK} for 60 sec.; then 1358 V_{PK} for 10 sec. with 5 pC partial discharge limit.

- Working Voltage (V_{IORM}; pollution degree 2):

Package	Part No. Suffix	Working Voltage
QSOP16	-1	600 V_{RMS}
Narrow-body SOIC16	-3	700 V_{RMS}
Wide-body SOIC16/True 8™	None	600 V_{RMS}

Safety-Limiting Values	Symbol	Value	Units
Safety rating ambient temperature	T_S	180	°C
Safety rating power (180 °C)	P_S	270	mW
Supply current safety rating (total of supplies)	I_S	54	mA

UL 1577 (Component Recognition Program File Number E207481)

V-Series isolation grade

6 kV rating; tested at 7.2 kV_{RMS} (10.2 kV_{PK}) for 1 second; each lot sample tested at 6 kV_{RMS} (8485 V_{PK}) for 1 minute.

Standard isolation grade

Each part tested at 3000 V_{RMS} (4243 V_{PK}) for 1 second; each lot sample tested at 2500 V_{RMS} (3536 V_{PK}) for 1 minute.

Soldering Profile

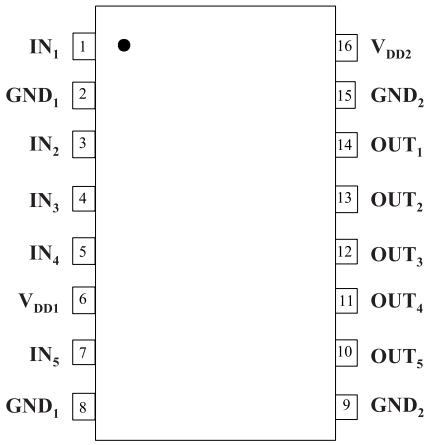
Per JEDEC J-STD-020C, MSL 1

NVE CORPORATION

IL260/IL261/IL262

IL260 Pin Connections

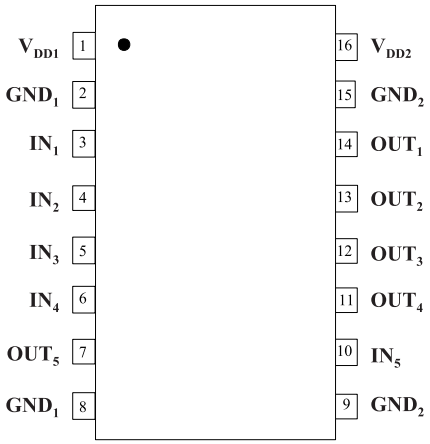
1	IN_1	Input 1
2	GND_1	Ground*
3	IN_2	Input 2
4	IN_3	Input 3
5	IN_4	Input 4
6	V_{DD1}	Supply Voltage 1
7	IN_5	Input 5
8	GND_1	Ground*
9	GND_2	Ground*
10	OUT_5	Output 5
11	OUT_4	Output 4
12	OUT_3	Output 3
13	OUT_2	Output 2
14	OUT_1	Output 1
15	GND_2	Ground*
16	V_{DD2}	Supply Voltage 2



IL260

IL261 Pin Connections

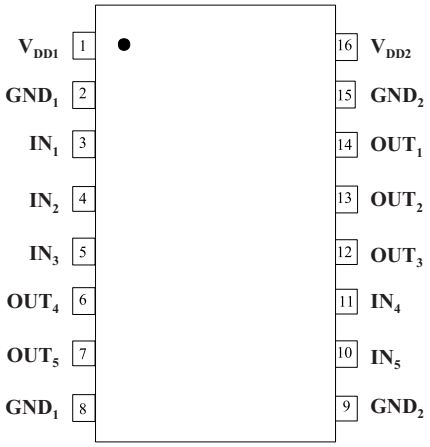
1	V_{DD1}	Supply Voltage 1
2	GND_1	Ground*
3	IN_1	Input 1
4	IN_2	Input 2
5	IN_3	Input 3
6	IN_4	Input 4
7	OUT_5	Output 5
8	GND_1	Ground*
9	GND_2	Ground*
10	IN_5	Input 5
11	OUT_4	Output 4
12	OUT_3	Output 3
13	OUT_2	Output 2
14	OUT_1	Output 1
15	GND_2	Ground*
16	V_{DD2}	Supply Voltage 2



IL261

IL262 Pin Connections

1	V_{DD1}	Supply Voltage 1
2	GND_1	Ground*
3	IN_1	Input 1
4	IN_2	Input 2
5	IN_3	Input 3
6	OUT_4	Output 4
7	OUT_5	Output 5
8	GND_1	Ground*
9	GND_2	Ground*
10	IN_5	Input 5
11	IN_4	Input 4
12	OUT_3	Output 3
13	OUT_2	Output 2
14	OUT_1	Output 1
15	GND_2	Ground*
16	V_{DD2}	Supply Voltage 2



IL262

***NOTE:** Pins 2 and 8 are internally connected, as are pins 9 and 15.

NVE Corporation 11409 Valley View Road, Eden Prairie, MN 55344-3617 (952) 829-9217 www.nve.com YouTube.com/NveCorporation isoapps@nve.com

3.3 Volt Electrical Specifications (T_{min} to T_{max})							
Parameters		**Symbol**	**Min.**	**Typ.**	**Max.**	**Units**	**Test Conditions**
Input Quiescent Current	IL260	I_{DD1}		300	400	µA	
	IL261			1.2	1.75	mA	
	IL262			2.4	3.5	mA	
Output Quiescent Current	IL260	I_{DD2}		6	8.75	mA	
	IL261			4.8	7	mA	
	IL262			3.6	5.25	mA	
Logic Input Current		I_i	−10		10	µA	
Logic High Output Voltage		V_{OH}	V_{DD}−0.1	V_{DD}		V	I_O = −20 µA, V_I=V_{IH}
			0.8 x V_{DD}	0.9 x V_{DD}			I_O = −4 mA, V_I=V_{IH}
Logic Low Output Voltage		V_{OL}		0	0.1	V	I_O = 20 µA, V_I=V_{IL}
				0.5	0.8		I_O = 4 mA, V_I=V_{IL}

Switching Specifications (2.7 V <V_{DD} < 3.6 V)						
Maximum Data Rate		100	110		Mbps	C_L = 15 pF
Minimum Pulse Width[7]	PW	10			ns	50% Points, V_O
Propagation Delay Input to Output (High to Low)	t_{PHL}		12	18	ns	C_L = 15 pF
Propagation Delay Input to Output (Low to High)	t_{PLH}		12	18	ns	C_L = 15 pF
Pulse Width Distortion $\lvert t_{PHL}-t_{PLH}\rvert$[2]	PWD		2	3	ns	C_L = 15 pF
Propagation Delay Skew[3]	t_{PSK}		4	6	ns	C_L = 15 pF
Output Rise Time (10%–90%)	t_R		2	4	ns	C_L = 15 pF
Output Fall Time (10%–90%)	t_F		2	4	ns	C_L = 15 pF
Common Mode Transient Immunity (Output Logic High to Logic Low)[4]	$\lvert CM_H\rvert$,$\lvert CM_L\rvert$	30	50		kV/µs	V_{CM} = 1500 V_{DC} $t_{TRANSIENT}$ = 25 ns
Channel-to-Channel Skew			2	3	ns	C_L = 15 pF
Dynamic Power Consumption[6]			140	240	µA/Mbps	per channel

Magnetic Field Immunity[8] (V_{DD2} = 3 V, 3 V < V_{DD1} < 5.5 V)						
Power Frequency Magnetic Immunity	H_{PF}		1500		A/m	50Hz/60Hz
Pulse Magnetic Field Immunity	H_{PM}		2000		A/m	t_p = 8µs
Damped Oscillatory Magnetic Field	H_{OSC}		2000		A/m	0.1Hz – 1MHz
Cross-axis Immunity Multiplier[9]	K_X		2.5			

5 Volt Electrical Specifications (T_{min} to T_{max})							
Parameters		**Symbol**	**Min.**	**Typ.**	**Max.**	**Units**	**Test Conditions**
Input Quiescent Current	IL260	I_{DD1}		350	500	µA	
	IL261			1.8	2.5	mA	
	IL262			3.6	5	mA	
Output Quiescent Current	IL260	I_{DD2}		9	12.5	mA	
	IL261			7.2	10	mA	
	IL262			5.4	7.5	mA	
Logic Input Current		I_i	−10		10	µA	
Logic High Output Voltage		V_{OH}	V_{DD}−0.1	V_{DD}		V	I_O = −20 µA, V_I = V_{IH}
			0.8 x V_{DD}	0.9 x V_{DD}			I_O = −4 mA, V_I = V_{IH}
Logic Low Output Voltage		V_{OL}		0	0.1	V	I_O = 20 µA, V_I = V_{IL}
				0.5	0.8		I_O = 4 mA, V_I = V_{IL}

Switching Specifications (V_{DD} = 5 V)						
Maximum Data Rate		100	110		Mbps	C_L = 15 pF
Minimum Pulse Width[7]	PW	10			ns	50% Points, V_O
Propagation Delay Input to Output (High to Low)	t_{PHL}		10	15	ns	C_L = 15 pF
Propagation Delay Input to Output (Low to High)	t_{PLH}		10	15	ns	C_L = 15 pF
Pulse Width Distortion $\lvert t_{PHL} - t_{PLH} \rvert$[2]	PWD		2	3	ns	C_L = 15 pF
Pulse Jitter[10]	t_J		100		ps	C_L = 15 pF
Propagation Delay Skew[3]	t_{PSK}		4	6	ns	C_L = 15 pF
Output Rise Time (10%–90%)	t_R		1	3	ns	C_L = 15 pF
Output Fall Time (10%–90%)	t_F		1	3	ns	C_L = 15 pF
Common Mode Transient Immunity (Output Logic High to Logic Low)[4]	$\lvert CM_H \rvert$,$\lvert CM_L \rvert$	30	50		kV/µs	V_{CM} = 1500 V_{DC} $t_{TRANSIENT}$ = 25 ns
Channel-to-Channel Skew			2	3	ns	C_L = 15 pF
Dynamic Power Consumption[6]			200	340	µA/Mbps	per channel

Magnetic Field Immunity[8] (V_{DD2} = 5 V, 3 V < V_{DD1} < 5.5V)						
Power Frequency Magnetic Immunity	H_{PF}		3500		A/m	50Hz/60Hz
Pulse Magnetic Field Immunity	H_{PM}		4500		A/m	t_p = 8µs
Damped Oscillatory Magnetic Field	H_{OSC}		4500		A/m	0.1Hz – 1MHz
Cross-axis Immunity Multiplier[9]	K_X		2.5			

Insulation Specifications							
Parameter		**Symbol**	**Min.**	**Typ.**	**Max.**	**Units**	**Test Conditions**
Creepage Distance (external)	QSOP 0.15" SOIC 0.3" SOIC		4.03 4.03 8.03	 8.3		mm	Per IEC 60601
Total Barrier Thickness (internal)			0.012	0.016		mm	
Leakage Current[5]				0.2		μA_{RMS}	240 V_{RMS}
Barrier Resistance[5]		R_{IO}		$>10^{14}$		Ω	500 V
Barrier Capacitance[5]		C_{IO}		5		pF	f = 1 MHz
Comparative Tracking Index		CTI	≥600			V_{RMS}	Per IEC 60112
High Voltage Endurance (Maximum Barrier Voltage for Indefinite Life)	AC DC	V_{IO}	1000 1500			V_{RMS} V_{DC}	At maximum operating temperature
Surge Immunity (“V” Versions)		V_{IOSM}	12.8			kV_{PK}	Per IEC 61000-4-5
Barrier Life				44000		Years	100°C, 1000 V_{RMS}, 60% CL activation energy

Thermal Characteristics							
Parameter		**Symbol**	**Min.**	**Typ.**	**Max.**	**Units**	**Test Conditions**
Junction–Ambient Thermal Resistance	QSOP 0.15" SOIC16 0.3" SOIC16	θ_{JA}		100 82 67		°C/W	Double-sided PCB in free air
Junction–Case (Top) Thermal Resistance	QSOP 0.15" SOIC16 0.3" SOIC16	θ_{JC}		9 8 12			
Junction–Ambient Thermal Resistance	0.3" SOIC	θ_{JA}		46			2s2p PCB in free air per JESD51
Junction–Case (Top) Thermal Resistance		θ_{JC}		9			
Power Dissipation	QSOP 0.15" SOIC16 0.3" SOIC16	P_D			675 675 1500	mW	

Notes:

1. Absolute maximum means the device will not be damaged if operated under these conditions. It does not guarantee performance.
2. PWD is defined as $|t_{PHL} - t_{PLH}|$. %PWD is equal to PWD divided by pulse width.
3. t_{PSK} is the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} between devices at 25°C.
4. CM_H is the maximum common mode voltage slew rate that can be sustained while maintaining $V_O > 0.8\ V_{DD2}$. CM_L is the maximum common mode input voltage that can be sustained while maintaining $V_O < 0.8$ V. The common mode voltage slew rates apply to both rising and falling common mode voltage edges.
5. Device is considered a two-terminal device: pins 1–8 shorted and pins 9–16 shorted.
6. Dynamic power consumption numbers are calculated per channel and are supplied by the channel’s input side power supply.
7. Minimum pulse width is the minimum value at which specified PWD is guaranteed.
8. The relevant test and measurement methods are given in the Electromagnetic Compatibility section on p. 8.
9. External magnetic field immunity is improved by this factor if the field direction is “end-to-end” rather than to “pin-to-pin” (see diagram on p. 8).
10. 66,535-bit pseudo-random binary signal (PRBS) NRZ bit pattern with no more than five consecutive 1s or 0s; 800 ps transition time.

Application Information

Electrostatic Discharge Sensitivity

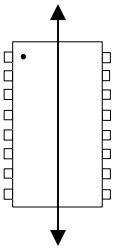
This product has been tested for electrostatic sensitivity to the limits stated in the specifications. However, NVE recommends that all integrated circuits be handled with appropriate care to avoid damage. Damage caused by inappropriate handling or storage could range from performance degradation to complete failure.

Electromagnetic Compatibility

IsoLoop Isolators have the lowest EMC footprint of any isolation technology. There are no internal clocks or carriers. IsoLoop Isolators' Wheatstone bridge configuration and differential magnetic field signaling ensure excellent EMC performance against all relevant standards.

These isolators are fully compliant with IEC 61000-6-1 and IEC 61000-6-2 standards for immunity, and IEC 61000-6-3, IEC 61000-6-4, CISPR, and FCC Class A standards for emissions.

Immunity to external magnetic fields is even higher if the field direction is "end-to-end" rather than to "pin-to-pin" as shown in the diagram below:



Cross-axis Field Direction

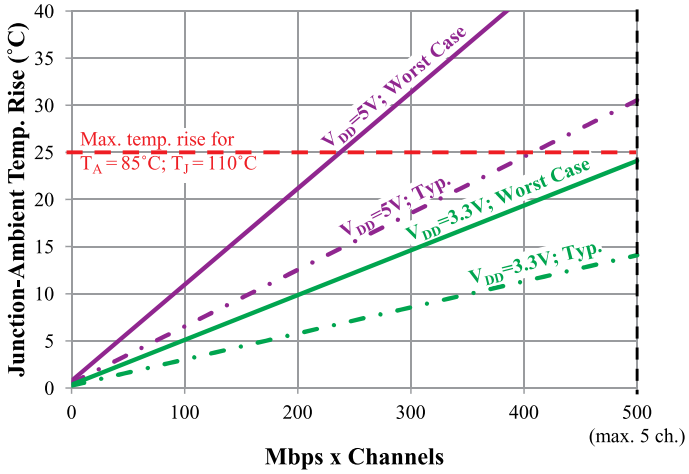
Dynamic Power Consumption

IsoLoop Isolators achieve their low power consumption from the way they transmit data across the isolation barrier. By detecting the edge transitions of the input logic signal and converting these to narrow current pulses, a magnetic field is created around the GMR Wheatstone bridge. Depending on the direction of the magnetic field, the bridge causes the output comparator to switch following the input logic signal. Since the current pulses are narrow, about 2.5 ns, the power consumption is independent of mark-to-space ratio and solely dependent on frequency. This has obvious advantages over optocouplers, which have power consumption heavily dependent on mark-to-space ratio.

Thermal Management

IsoLoop Isolators are designed for low power dissipation and thermal performance, providing unmatched channel density for high-performance isolators. Nevertheless, package temperature rise should be considered when running multiple channels at high speed. Power consumption is higher at 5 volt operation than at 3.3 volts, and dynamic supply current is higher on the input side of the isolators than the output side, so thermal management is more important with five-volt input-side power supplies.

IL260/IL261/IL262 parts have a maximum junction temperature of 110°C. Based on the specifications contained in this datasheet, the derating curve at typical operating conditions is as follows:



Power Supply Decoupling

Both power supplies should be bypassed with 0.1 µF typical (0.047 µF minimum) capacitors as close as possible to the V_{DD} pins. Ground planes for both GND_1 and GND_2 are highly recommended for data rates above 10 Mbps.

Maintaining Creepage

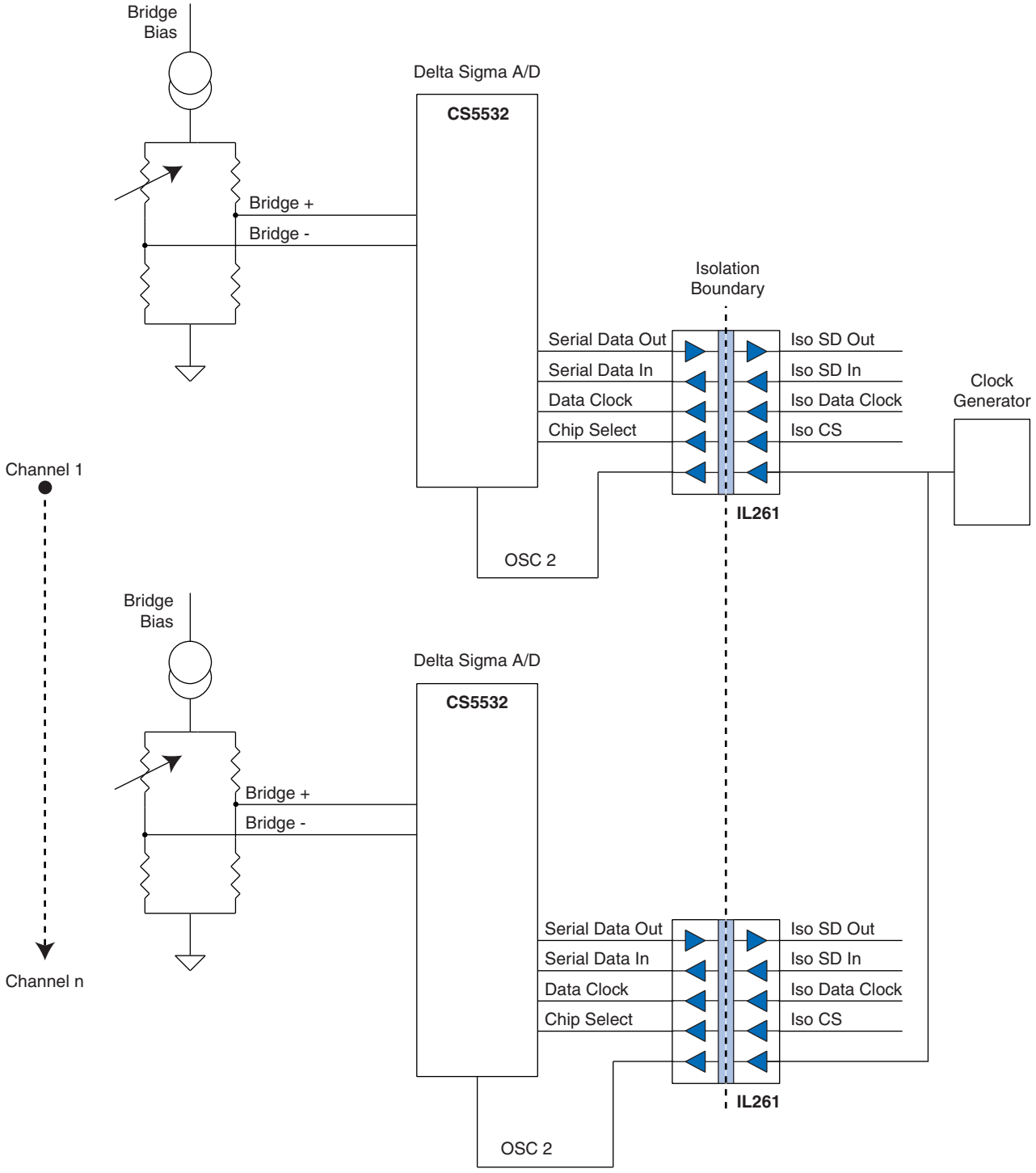
Creepage distances are often critical in isolated circuits. In addition to meeting JEDEC standards, NVE isolator packages have unique creepage specifications. Standard pad libraries often extend under the package, compromising creepage and clearance. Similarly, ground planes, if used, should be spaced to avoid compromising clearance. Package drawings and recommended pad layouts are included in this datasheet.

Signal Status on Start-up and Shut Down

To minimize power dissipation, input signals are differentiated and then latched on the output side of the isolation barrier to reconstruct the signal. This could result in an ambiguous output state depending on power up, shutdown and power loss sequencing. Therefore, the designer should consider including an initialization signal in the start-up circuit. Initialization consists of toggling the input either high then low, or low then high.

Application Diagram—Multi-Channel Delta-Sigma A/D Converter

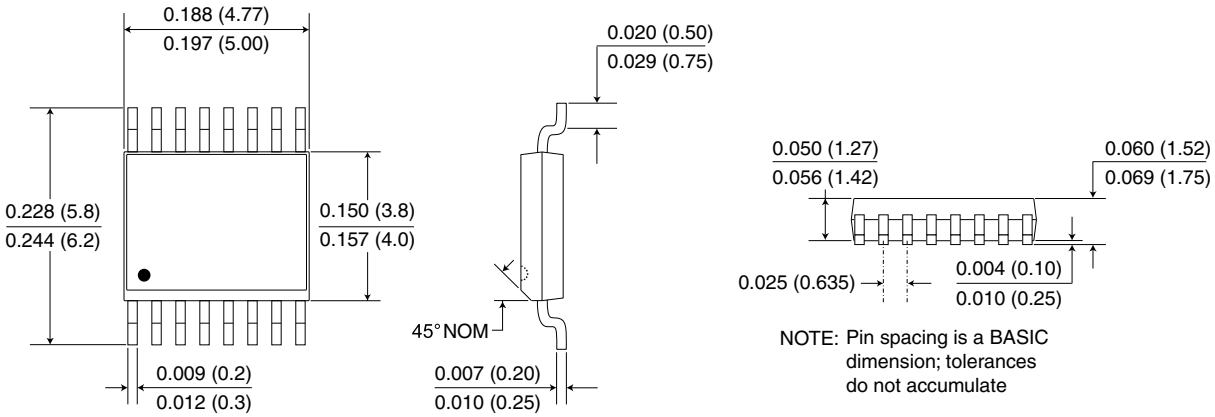
In a typical single-channel delta-sigma ADC, the system clock is located on the isolated side of the system and only four channels of isolation are required. With multiple ADCs configured in a channel-to-channel isolation configuration, however, clock jitter and edge placement accuracy of the system clock must be matched between ADCs. The best solution is to use a single clock on the system side and distribute the clock to each ADC. The five-channel IL261 is ideal, with the fifth channel used to distribute a single, isolated clock to multiple ADCs as shown below:



Package Drawings

Ultraminiature 16-pin QSOP Package (-1 suffix)

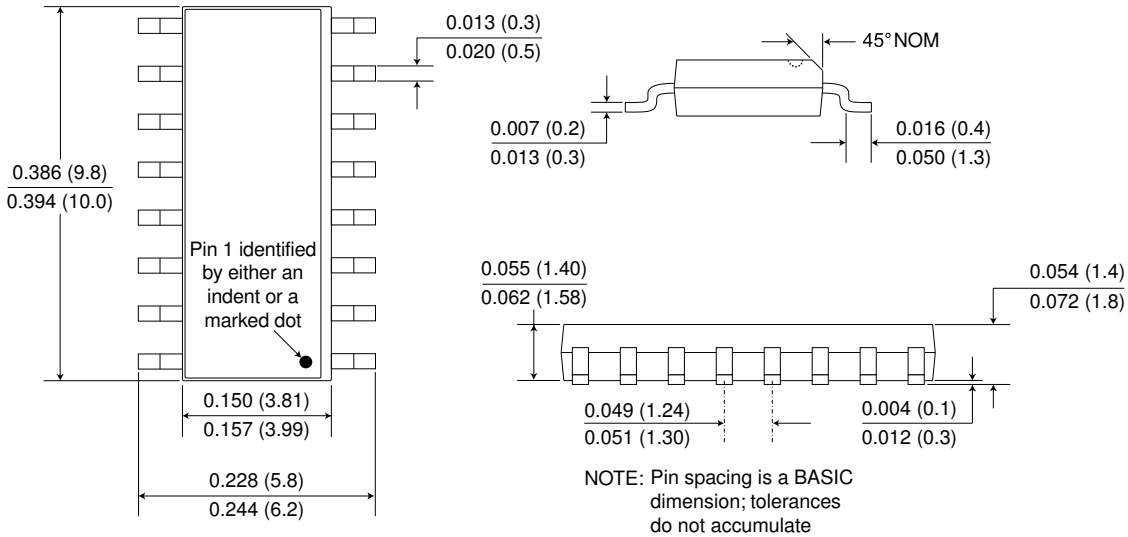
Dimensions in inches (mm); scale = approx. 5X



NOTE: Pin spacing is a BASIC dimension; tolerances do not accumulate

0.15" 16-pin SOIC Package (-3 suffix)

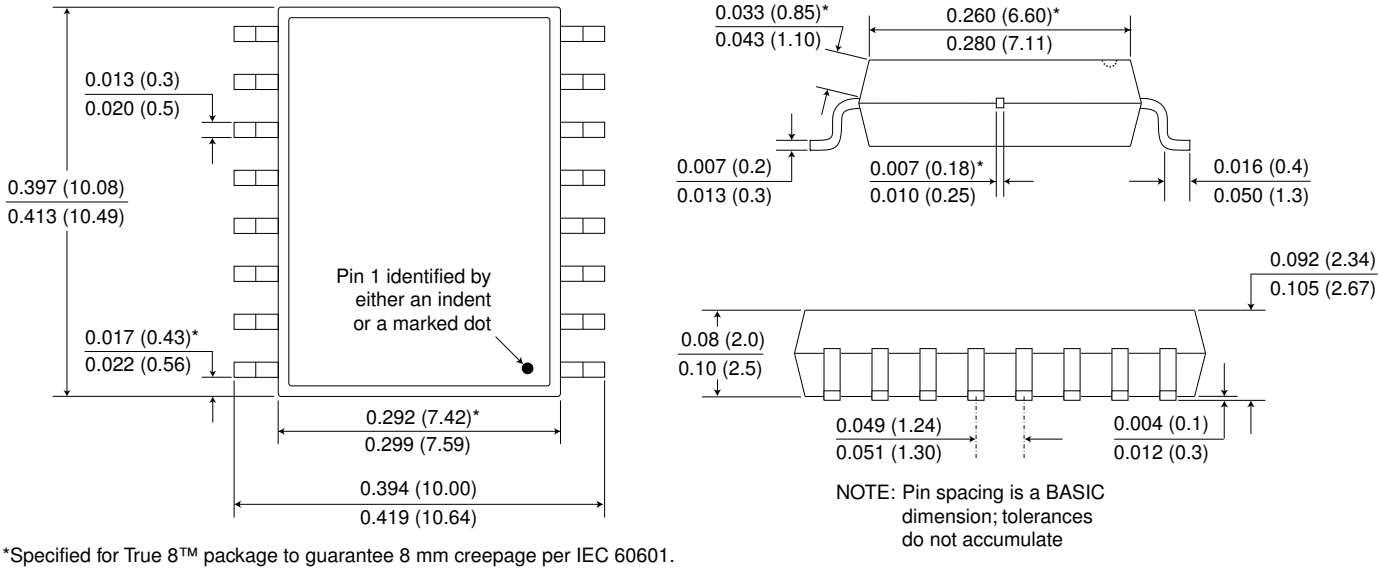
Dimensions in inches (mm); scale = approx. 5X



NOTE: Pin spacing is a BASIC dimension; tolerances do not accumulate

0.3" 16-pin SOIC Package (no suffix)

Dimensions in inches (mm); scale = approx. 5X



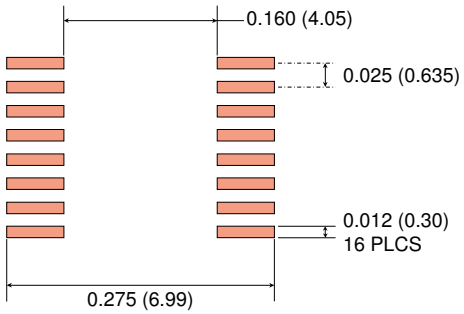
NOTE: Pin spacing is a BASIC dimension; tolerances do not accumulate

*Specified for True 8™ package to guarantee 8 mm creepage per IEC 60601.

Recommended Pad Layouts

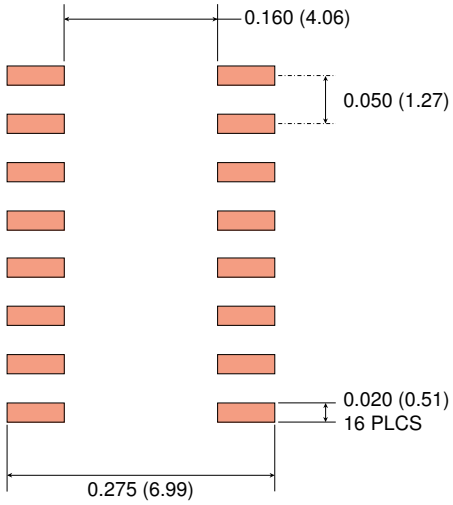
4 mm x 5 mm 16-pin QSOP Pad Layout

Dimensions in inches (mm); scale = approx. 5X

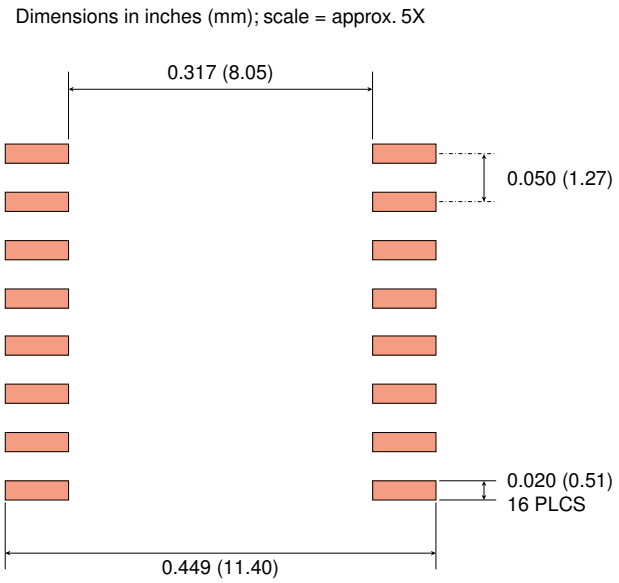


0.15" 16-pin SOIC Pad Layout

Dimensions in inches (mm); scale = approx. 5X



0.3" 16-pin SOIC Pad Layout



Available Parts

Available Parts	Transmit Channels	Receive Channels	Isolation Voltage (RMS)	Package
IL260-1E	5	0	2.5 kV	QSOP
IL260-3E	5	0	2.5 kV	Narrow SOIC
IL260E	5	0	2.5 kV	Wide SOIC
IL260VE	5	0	6 kV	Wide SOIC
IL261-1E	4	1	2.5 kV	QSOP
IL261-3E	4	1	2.5 kV	Narrow SOIC
IL261E	4	1	2.5 kV	Wide SOIC
IL261VE	4	1	6 kV	Wide SOIC
IL262-3E	3	2	2.5 kV	Narrow SOIC
IL262E	3	2	2.5 kV	Wide SOIC
IL262VE	3	2	6 kV	Wide SOIC

All part types are available on tape and reel.

Part Numbering

IL 260 - 3 E TR13

Bulk Package
Blank = Tube
TR7 = 7" Tape and Reel
TR13 = 13" Tape and Reel

Package
Blank = 80/20 Tin/Lead Plating
E = RoHS Compliant

Package Type
Blank = 0.3" 16-pin SOIC
-3 = 0.15" 16-pin SOIC

Base Part Number
260 = 5 Drive Channels
261 = 4 Drive Channels, 1 Receive Channel
262 = 3 Drive Channels, 2 Receive Channel

Product Family
IL = Isolators

RoHS COMPLIANT

Revision History

ISB-DS-001-IL260/1/2-Y
February 2023

Changes
- Increased minimum supply voltage from 2.5 V to 2.7 V (p. 2).
- Eliminated redundant “valid part numbers” list (p. 14).

ISB-DS-001-IL260/1/2-X

Changes
- Upgraded to IEC 60747-17 (VDE 0884-17):2021-10 (p. 3).
- Increased Working Voltage ratings based on latest VDE testing (p. 3).

ISB-DS-001-IL260/1/2-W

Changes
- Reduced minimum supply voltage to 2.5 V (p. 2).
- Updated EMC standards.
- Deleted minimum magnetic field immunity specifications (not 100% tested).
- Updated thermal specifications (p. 7).

ISB-DS-001-IL260/1/2-V

Change
- VDE certification and UL approval for V-Series versions (6 kV reinforced isolation).

ISB-DS-001-IL260/1/2-U

Changes
- Updated VDE certification standard to VDE V 0884-10.
- Upgraded “VE” Version Surge Immunity specification to 12.8 kV.
- Upgraded “VE” Version VDE 0884-10 rating to reinforced insulation.
- Corrected QSOP pin width dimension (p. 10).

ISB-DS-001-IL260/1/2-T

Changes
- Increased V-Series isolation voltage to 6 kVrms.
- Increased typ. Total Barrier Thickness specification to 0.016 mm.
- Increased CTI min. specification to ≥600 V_{RMS}.

ISB-DS-001-IL260/1/2-S

Changes
- Added V-Series 5 kV isolation voltage versions.
- More detailed “Available Parts” table.

ISB-DS-001-IL260/1/2-R

Changes
- Added QSOP packages (-1 suffix).
- Revised and added details to thermal characteristic specifications (p. 2).
- Added VDE 0884 Safety-Limiting Values (p. 3).
- Added “Thermal Management” paragraph in Applications section.

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ISB-DS-001-IL260/1/2-Y

February 2023

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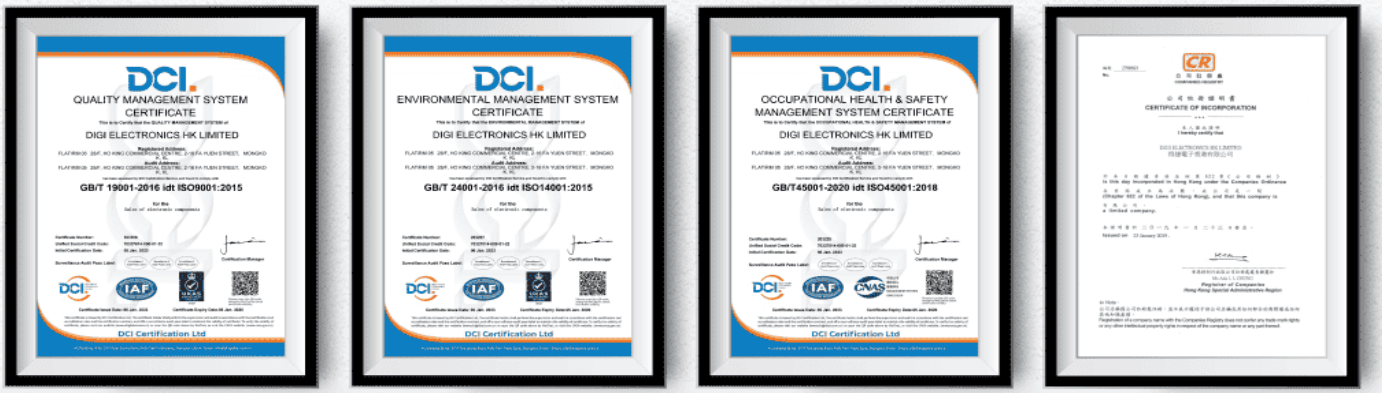

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